



SOT23

ABSOLUTE MAXIMUM RATINGS.

PARAMETER	SYMBOL	VALUE			UNIT
Drain-Source Voltage	V_{DS}		60		V
Continuous Drain Current at $T_{amb}=25^{\circ}C$	I_D		0.15		mA
Pulsed Drain Current	I_{DM}		3		A
Gate Source Voltage	V_{GS}		± 20		V
Power Dissipation at $T_{amb}=25^{\circ}C$	P_{tot}		330		mW
Operating and Storage Temperature Range	$T_j \cdot T_{stg}$		-55 to +150		$^{\circ}C$

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS.
Drain-Source Breakdown Voltage	BV_{DSS}	60	90		V	$I_D=100\mu A, V_{GS}=0V$
Gate-Source Threshold Voltage	$V_{GS(th)}$	0.8		3	V	$I_D=1mA, V_{DS}=V_{GS}$
Gate-Body Leakage	I_{GSS}			10	nA	$V_{GS}=15V, V_{DS}=0V$
Zero Gate Voltage Drain Current	I_{DSS}			0.5	μA	$V_{DS}=25V, V_{GS}=0V$
Static Drain-Source On-State Resistance (1)	$R_{DS(on)}$			5	Ω	$V_{GS}=10V, I_D=200mA$
Forward Transconductance (1)(2)	g_{fs}		200		mS	$V_{DS}=10V, I_D=200mA$
Input Capacitance (2)	C_{iss}		60		pF	$V_{DS}=10V, V_{GS}=0V, f=1MHz$
Turn-On Delay Time (2)(3)	$t_{d(on)}$			10	ns	$V_{DD} \approx -15V, I_D=600mA$
Turn-Off Delay Time (2)(3)	$t_{d(off)}$			10	ns	